

L Number	Hits	Search Text	DB	Time stamp
7	92	@ad<=20010323 and 'epi' and 'silicon gate'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/26 11:54
8	9	@ad<=20010323 and 'epitaxial silicon gate'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/26 11:10
9	1	("6528363").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/26 11:10
24	7	@ad<=20010323 and 'conductor' same 'epi' same 'polysilicon' same 'amorphous'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/26 12:04
25	0	@ad<=20010323 and 'conductive' same 'epi' same 'polysilicon' same 'amorphous'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/26 12:04
-	10	((("5393681") or ("6391692") or ("5308782") or ("5998248") or ("6319782"))).PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/25 13:55
-	162	257/929 and @ad<=20010323	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/25 14:15
-	542	438/300 and @ad<=20010323	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/20 08:38
-	4	@ad<=20010323 and 'raised vertical lateral transistor'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/04 16:02
-	1	@ad<=20010323 and 'raised source and drain'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/04 15:26
-	1	@ad<=20010323 and 'epitaxial' and 'source or drain'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/04 15:30
-	8	@ad<=20010323 and 'epitaxial' and 'source and drain'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/04 15:30
-	3470	gardner.inv.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/04 15:45
-	6	gardner.inv. and 'vertical transistor' and @ad<=20010323	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/04 15:48

-	4	@ad<=20010323 and 'elevated source and drain'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/25 14:24
-	257	@ad<=20010323 and 'elevated source'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/04 16:06
-	37	@ad<=20010323 and 'epitaxial' with 'elevated source'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/20 08:56
-	1	"4728623".PN.	USPAT	2002/09/04 16:31
-	1	"4738937".PN.	USPAT	2002/09/04 16:31
-	1	"4918029".PN.	USPAT	2002/09/04 16:31
-	1	"5004702".PN.	USPAT	2002/09/04 16:31
-	1	"5030583".PN.	USPAT	2002/09/04 16:31
-	1	"5032538".PN.	USPAT	2002/09/04 16:31
-	1	"5045494".PN.	USPAT	2002/09/04 16:31
-	1	"5272109".PN.	USPAT	2002/09/04 16:32
-	1	"5496750".PN.	USPAT	2002/09/04 16:38
-	1	"5378651".PN.	USPAT	2002/09/04 16:38
-	1	"5321306".PN.	USPAT	2002/09/04 16:38
-	1	"5296388".PN.	USPAT	2002/09/04 16:38
-	1	"5250454".PN.	USPAT	2002/09/04 16:39
-	1	"5213991".PN.	USPAT	2002/09/04 16:39
-	1	"5079180".PN.	USPAT	2002/09/04 16:39
-	1	"5057899".PN.	USPAT	2002/09/04 16:39
-	1	"4966861".PN.	USPAT	2002/09/04 16:41
-	1	"4814841".PN.	USPAT	2002/09/04 16:48
-	1	"5057893".PN.	USPAT	2002/09/04 16:48
-	18	((("6096596") or ("6090691") or ("6057200") or ("6001697") or ("5998844") or ("5963822") or ("5945698") or ("5933738") or ("5863826"))).PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/05 08:23
-	18	((("5831334") or ("5677573") or ("5641694") or ("5600161") or ("5497017") or ("5312768") or ("5156987") or ("5122476") or ("5087586"))).PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/05 10:18
-	2	("5308782").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/05 10:19
-	2	("6319782").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/05 10:19
-	1731	((438/300) or (257/302) or (257/929) or (257/592)).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/20 08:44
-	12	ri-seiko.in.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/20 08:44
-	38	@ad<=20010323 and 'epitaxial' with 'elevated source'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/20 09:33

-	263	@ad<=20010323 and 'elevated source'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/20 09:33
-	263	@ad<=20010323 and elevated adj1 source	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/20 09:02
-	95	@ad<=20010323 and elevated adj1 drain	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/20 09:02
-	112	@ad<=20010323 and raised adj1 drain	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/20 09:03
-	229	@ad<=20010323 and raised adj1 source	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/20 09:03
-	0	@ad<=20010323 and 'epitaxial silicon gate' with 'elevated source'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/20 09:38
-	20	@ad<=20010323 and 'silicon gate' and 'elevated source'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/20 09:38
-	47	@ad<=20010323 and 'polysilicon gate' and 'elevated source'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/03/25 14:14
-	0	@ad<=20010323 and 'epitaxial polysilicon gate' and 'elevated source'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/03/25 14:25
-	1	@ad<=20010323 and 'epitaxial polysilicon' and 'elevated source'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/20 10:08
-	56	@ad<=20010323 and 'epitaxial polysilicon'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/21 08:20
-	0	@ad<=20010323 and 'epitaxial polysilicon gate'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/20 14:05
-	24	@ad<=20010323 and 'epitaxial gate'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/20 14:05
-	24	@ad<=20010323 and 'epitaxial gate'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/21 08:30

-	560	@ad<=20010323 and polysilicon with epitaxial with gate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/20 16:16
-	2348	@ad<=20010323 and 'multilayer' same 'gate'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/21 08:55
-	260	(@ad<=20010323 and 'multilayer' same 'gate') and 'epitaxial'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/20 16:18
-	0	@ad<=20010323 and 'multilayer gate' with 'epitaxial'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/20 16:33
-	1	@ad<=20010323 and epitaxial near grow near polysilicon	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/21 08:20
-	693	@ad<=20010323 and 'epitaxial silicon' same 'gate'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/21 08:32
-	367	@ad<=20010323 and 'epitaxial silicon' with 'gate'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/21 08:41
-	9	@ad<=20010323 and 'epitaxial silicon gate'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/03/26 10:14
-	1	@ad<=20010323 and 'multilayer silicon gate'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/11/21 08:56
-	1	("6534809").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/03/25 13:55
-	564	@ad<=20010323 and 'polysilicon gate' same 'epitaxial'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/03/25 14:18
-	390	(257/756).cccls and @ad<=20010323	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/03/25 14:16
-	214	@ad<=20010323 and 'floating gate' same 'epitaxial'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/03/25 14:18
-	2141	@ad<=20010323 and 'elevated' same 'source' and 'drain'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/03/25 14:28

-	413	@ad<=20010323 and 'elevated' with 'source' with 'drain'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/25 14:28
-	6	@ad<=20010323 and 'epi silicon' and 'elevated' same 'source'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/26 11:54
-	1	"4074300".PN.	USPAT	2003/03/25 14:37
-	32	@ad<=20010323 and 'gate stack' and 'elevated' same 'source'	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/25 15:13
-	8	((("4583105") or ("6083815") or ("5885877") or ("5986328")).PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/25 15:39
-	2	("5198378").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/03/25 15:39